

Notice of References Cited

Application/Control No.

10/045,278

Applicant(s)/Patent Under
Reexamination
GEHRING ET AL.

Examiner

Marcos D. Pizarro-Crespo

Art Unit

2814

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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NON-PATENT DOCUMENTS

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
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